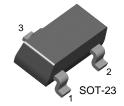


## KST4124

## **General Purpose Transistor**



1. Base 2. Emitter 3. Collector

## **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	200	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	150	°C

Refer to KST3904 for graphs

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =10μA, I <sub>E</sub> =0	30		V
BV <sub>CEO</sub>	* Collector-Emitter Breakdown Voltage	I <sub>C</sub> =1.0mA, I <sub>B</sub> =0	25		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =20V, I <sub>E</sub> =0		50	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =3V, I <sub>C</sub> =0		50	nA
h <sub>FE</sub>	* DC Current Gain	$V_{CE}=1V$ , $I_{C}=2mA$ $V_{CE}=1V$ , $I_{C}=50mA$	120 60	360	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA		0.3	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA		0.95	V
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> =10mA, V <sub>CE</sub> =20V f=100MHz	300		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =5V, I <sub>E</sub> =0, f=1.0MHz		4	pF
NF	Noise Figure	$I_C$ =100μA, $V_{CE}$ =5V $R_S$ =1K $\Omega$ f=10Hz to 15.7KHz		5	dB

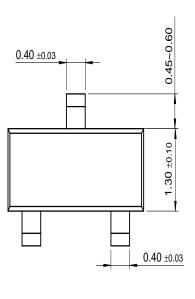
<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

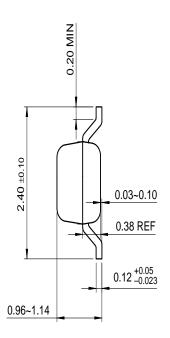


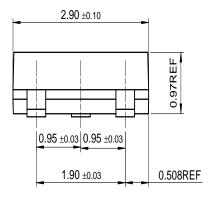
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# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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